

SN54LV573A, SN74LV573A OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

SCLS411C – APRIL 1998 – REVISED MAY 2000

- **EPIC™ (Enhanced-Performance Implanted CMOS) Process**
- **Typical V_{OLP} (Output Ground Bounce)**
<0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- **Typical V_{OHV} (Output V_{OH} Undershoot)**
>2.3 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- **2-V to 5.5-V V_{CC} Operation**
- **Support Mixed-Mode Voltage Operation on All Ports**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)**
- **Package Options Include Plastic Small-Outline (DW, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)**

description

The 'LV573A devices are octal transparent D-type latches designed for 2-V to 5.5-V V_{CC} operation.

These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

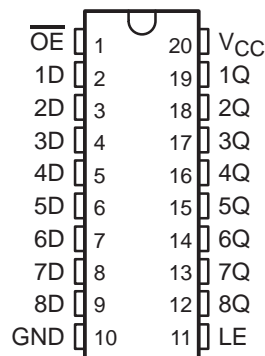
A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

\overline{OE} does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

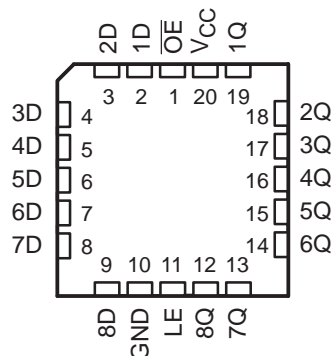
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LV573A is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LV573A is characterized for operation from -40°C to 85°C .

SN54LV573A . . . J OR W PACKAGE
SN74LV573A . . . DB, DGV, DW, NS, OR PW PACKAGE
(TOP VIEW)



SN54LV573A . . . FK PACKAGE
(TOP VIEW)



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**TEXAS
INSTRUMENTS**

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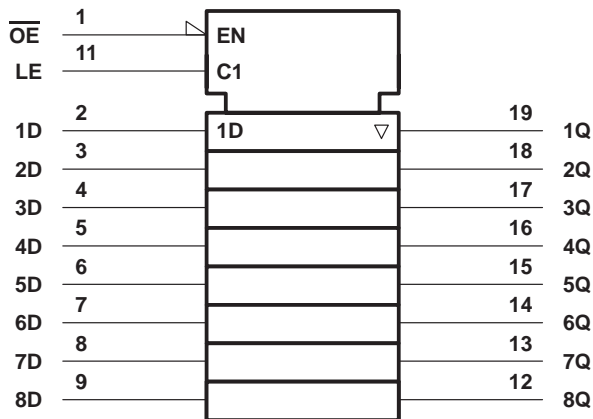
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(each latch)

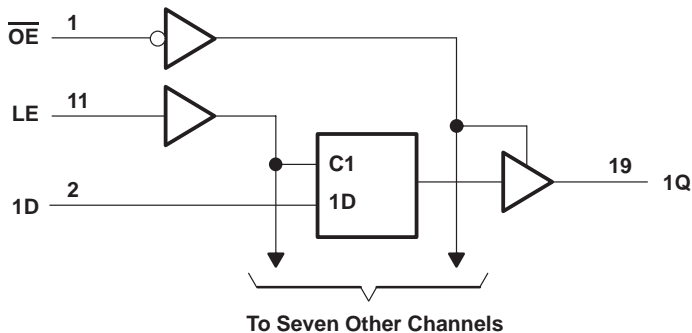
INPUTS			OUTPUT Q
\overline{OE}	LE	D	
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



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Supply voltage range, V_{CC}	-0.5 V to 7 V
Input voltage range, V_I (see Note 1)	-0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	-0.5 V to 7 V
Output voltage range applied in the high or low state, V_O (see Notes 1 and 2)	-0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	-20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	± 50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	± 35 mA
Continuous current through V_{CC} or GND	± 70 mA
Package thermal impedance, θ_{JA} (see Note 3):		
DB package	70°C/W
DGV package	92°C/W
DW package	58°C/W
NS package	60°C/W
PW package	83°C/W
Storage temperature range, T_{Stg}	-65°C to 150°C

3. The package thermal impedance is calculated in accordance with JEDEC 51.

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recommended operating conditions (see Note 4)

			SN54LV573A		SN74LV573A		UNIT
			MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		2	5.5	2	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5		1.5		V
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		V _{CC} × 0.7		
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		V _{CC} × 0.7		
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7		V _{CC} × 0.7		
V _{IL}	Low-level input voltage	V _{CC} = 2 V	0.5		0.5		V
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.3		V _{CC} × 0.3		
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.3		V _{CC} × 0.3		
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.3		V _{CC} × 0.3		
V _I	Input voltage		0	5.5	0	5.5	V
V _O	Output voltage	High or low state	0	V _{CC}	0	V _{CC}	V
		3-state	0	5.5	0	5.5	
I _{OH}	High-level output current	V _{CC} = 2 V	−50		−50		μA
		V _{CC} = 2.3 V to 2.7 V	−2		−2		mA
		V _{CC} = 3 V to 3.6 V	−8		−8		
		V _{CC} = 4.5 V to 5.5 V	−16		−16		
I _{OL}	Low-level output current	V _{CC} = 2 V	50		50		μA
		V _{CC} = 2.3 V to 2.7 V	2		2		mA
		V _{CC} = 3 V to 3.6 V	8		8		
		V _{CC} = 4.5 V to 5.5 V	16		16		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 2.3 V to 2.7 V	0	200	0	200	ns/V
		V _{CC} = 3 V to 3.6 V	0	100	0	100	
		V _{CC} = 4.5 V to 5.5 V	0	20	0	20	
T _A	Operating free-air temperature		−55	125	−40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	SN54LV573A			SN74LV573A			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V _{OH}	I _{OH} = −50 μA	2 V to 5.5 V	V _{CC} −0.1			V _{CC} −0.1			V
	I _{OH} = −2 mA	2.3 V	2			2			
	I _{OH} = −8 mA	3 V	2.48			2.48			
	I _{OH} = −16 mA	4.5 V	3.8			3.8			
V _{OL}	I _{OL} = 50 μA	2 V to 5.5 V	0.1			0.1			V
	I _{OL} = 2 mA	2.3 V	0.4			0.4			
	I _{OL} = 8 mA	3 V	0.44			0.44			
	I _{OL} = 16 mA	4.5 V	0.55			0.55			
I _I	V _I = V _{CC} or GND	0 V to 5.5 V	±1			±1			μA
I _{OZ}	V _O = V _{CC} or GND	5.5 V	±5			±5			μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V	20			20			μA
I _{off}	V _I or V _O = 0 to 5.5 V	0 V	5			5			μA
C _i	V _I = V _{CC} or GND	3.3 V	1.8			1.8			pF

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timing requirements over recommended operating free-air temperature range, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER			$T_A = 25^\circ\text{C}$		SN54LV573A		SN74LV573A		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_W	Pulse duration	LE high	6.5		6.5		6.5		ns
t_{su}	Setup time	Data before LE↓	5		5		5		ns
t_h	Hold time	Data after LE↓	2		2		2		ns

timing requirements over recommended operating free-air temperature range, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER			$T_A = 25^\circ\text{C}$		SN54LV573A		SN74LV573A		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_W	Pulse duration	LE high	5		5		5		ns
t_{su}	Setup time	Data before LE↓	3.5		3.5		3.5		ns
t_h	Hold time	Data after LE↓	1.5		1.5		1.5		ns

timing requirements over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER			$T_A = 25^\circ\text{C}$		SN54LV573A		SN74LV573A		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_W	Pulse duration	LE high	5		5		5		ns
t_{su}	Setup time	Data before LE↓	3.5		3.5		3.5		ns
t_h	Hold time	Data after LE↓	1.5		1.5		1.5		ns

switching characteristics over recommended operating free-air temperature range, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54LV573A		SN74LV573A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{pd}	D	Q	$C_L = 15\text{ pF}$	8.9*	15.8*		1*	18*	1	18	ns
	LE	Q		9.6*	16.2*		1*	19*	1	19	
t_{en}	\overline{OE}	Q		9.3*	16.2*		1*	19*	1	19	
t_{dis}	\overline{OE}	Q		6.7*	12.6*		1*	15*	1	15	
t_{pd}	D	Q	$C_L = 50\text{ pF}$	10.9	18.7		1	21	1	21	ns
	LE	Q		11.6	19.1		1	23	1	23	
t_{en}	\overline{OE}	Q		11.4	19		1	22	1	22	
t_{dis}	\overline{OE}	Q		8.6	17.3		1	19	1	19	
$t_{sk(o)}$					2					2	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

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**switching characteristics over recommended operating free-air temperature range,
V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54LV573A		SN74LV573A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{pd}	D	Q	C _L = 15 pF	6.2*	11*		1*	13*	1	13	ns
	LE	Q		6.8*	11.9*		1*	14*	1	14	
t _{en}	\overline{OE}	Q		6.6*	11.5*		1*	13.5*	1	13.5	
t _{dis}	\overline{OE}	Q		4.9*	11*		1*	13*	1	13	
t _{pd}	D	Q	C _L = 50 pF	7.7	14.5		1	16.5	1	16.5	ns
	LE	Q		8.2	15.4		1	17.5	1	17.5	
t _{en}	\overline{OE}	Q		8	15		1	17	1	17	
t _{dis}	\overline{OE}	Q		6.2	14.5		1	16.5	1	16.5	
t _{sk(o)}					1.5					1.5	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

**switching characteristics over recommended operating free-air temperature range,
V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54LV573A		SN74LV573A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{pd}	D	Q	C _L = 15 pF	4.3*	6.8*	1*	8*	1	8	ns	
	LE	Q		4.7*	7.7*	1*	9*	1	9		
t _{en}	\overline{OE}	Q		4.7*	7.7*	1*	9*	1	9		
t _{dis}	\overline{OE}	Q		3.5*	7.7*	1*	9*	1	9		
t _{pd}	D	Q	C _L = 50 pF	5.3	8.8	1	10	1	10	ns	
	LE	Q		5.7	9.7	1	11	1	11		
t _{en}	\overline{OE}	Q		5.7	9.7	1	11	1	11		
t _{dis}	\overline{OE}	Q		4.2	9.7	1	11	1	11		
t _{sk(o)}				1			1				

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 5)

PARAMETER		SN74LV573A			UNIT
		MIN	TYP	MAX	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.6	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		−0.5	−0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.9		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage		0.99		V

NOTE 5: Characteristics are for surface-mount packages only.

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operating characteristics, $T_A = 25^\circ\text{C}$

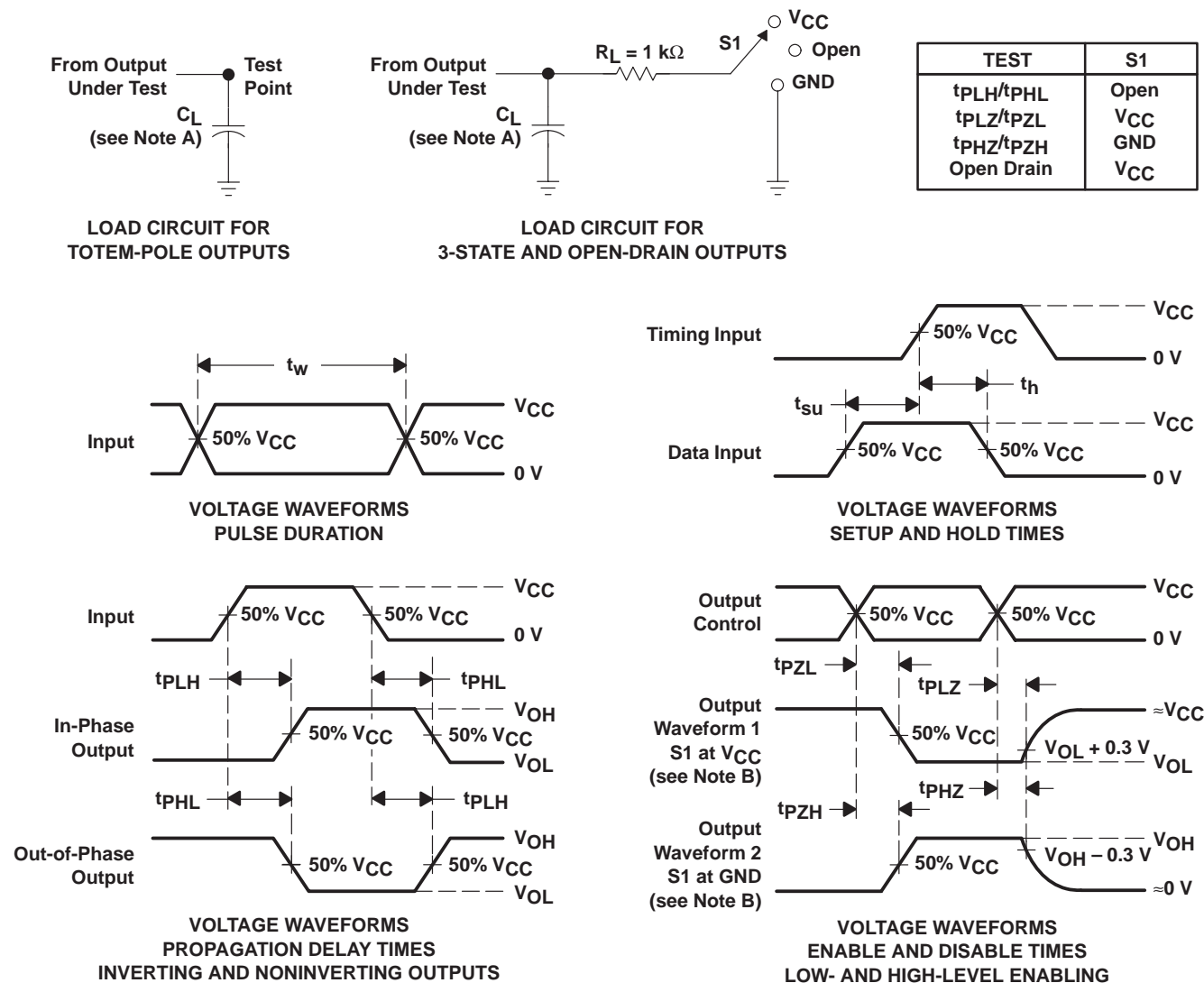
PARAMETER			TEST CONDITIONS	V _{CC}	TYP	UNIT
C _{pd}	Power dissipation capacitance	Outputs enabled	C _L = 50 pF, f = 10 MHz	3.3 V	16	pF
				5 V	18	
		LE to Q		3.3 V	18.2	
				5 V	21.3	



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PARAMETER MEASUREMENT INFORMATION



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
 - The outputs are measured one at a time with one input transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PHL} and t_{PLH} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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